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Unit in mm

7.62 ± 0.25

11-10C4

11-10C4

TOSHIBA Photocoupler GaAlAs Ired & Photo-IC

TLP250

Transistor Inverter Inverter For Air Conditioner **IGBT Gate Drive** Power MOS FET Gate Drive

The TOSHIBA TLP250 consists of a GaAlAs light emitting diode and a integrated photodetector.

This unit is 8-lead DIP package.

TLP250 is suitable for gate driving circuit of IGBT or power MOS FET.

- Input threshold current: IF=5mA(max.)
- Supply current (ICC): 11mA(max.)
- Supply voltage (V_{CC}): 10-35V
- Output current (IO): ±1.5A (max.)
- Switching time (t_{pLH}/t_{pHL}): 0.5µs(max.)
- Isolation voltage: 2500V_{rms}(min.)
- UL recognized: UL1577, file No.E67349
- Option(D4)

VDE Approved: DIN EN60747-5-2

Maximum Operating Insulation Voltage: 890 VPK

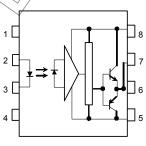
Please designate "Option(D4)"

(Note): When a EN60747-5-2 approved type is needed,

Highest Permissible Over Voltage

Weight: 0.54 g (typ.) : 4000VPK

Pin Configuration (top view)



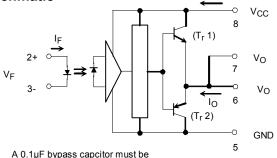
TOSHIBA

- 1: N.C.
- 5 : GND 2: Anode 6 : VO (Output)
- 3 : Cathode 4 : N.C.
- 7 : V_O 8 : V_{CC}

Truth Table

		Tr1	Tr2
Input LED	On	On	Off
	Off	Off	On





connected between pin 8 and 5 (See Note 5).

Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit	
	Forward current	l _F	20	mA	
	Forward current derating (Ta ≥ 70°C)	ΔI _F / ΔTa	-0.36	mA / °C	
LED	Peak transient forward curent	I _{FPT}	1	Α	
	Reverse voltage		V _R	5	V
	Junction temperature		Tj	125	°C
	"H"peak output current ($P_W \le 2.5 \mu s, f \le 15 kHz$)	I _{OPH}	(-1.5)	> A	
	"L"peak output current ($P_W \le 2.5 \mu s, f \le 15 kHz$)	(Note 2)	I _{OPL}	+1.5	Α
ector	Output voltage	(Ta ≤ 70°C)	VO	// 35	V
	Output voitage	(Ta = 85°C)		24	V
	Supply voltage	(Ta ≤ 70°C)	Vac	35	V
	Supply Voltage	(Ta = 85°C)	Vac	24	,
	Output voltage derating (Ta ≥ 70°C)		ΔV _Ο ΔΤα	-0.73	AY.c
	Supply voltage derating (Ta ≥ 70°C)		ΔV _{CC} / ΔTa	-0.73	1/ NJ.E
	Junction temperature		7)\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	125	∵%C
Operating frequency		(Note 3)	/)) f		kHz
Operating temperature range			T _{opr}	-20~85	ı//c
Storage temperature range		20	> T _{stg}	=55~125	°C
Lead	soldering temperature (10 s)	4	T _{sol}	260	°C
Isolation voltage (AC, 1 min., R.H.≤ 60%) (Note			BVS	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.)

Note 1: Pulse width P_W ≤ 1µs, 300pps

Note 2: Exporenential waveform

Note 3: Exporenential waveform, $lop_H \le -1.0A (\le 2.5 \mu s)$, $lop_L \le +1.0A (\le 2.5 \mu s)$

Note 4: Device considerd a two terminal device: Pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.

Note 5: A ceramic capacitor(0.1µF) should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching proparty. The total lead length between capacitor and coupler should not exceed 1cm.

Recommended Operating Conditions

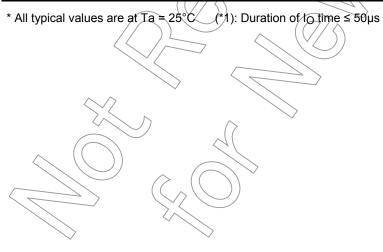
Characteristic		Symbol	Min	Тур.	Ma	ax	Unit
Input current, on	(Note6)	(I _{F(ON)})	7	8	1	0	mA
Input voltage, off	5	VF(OFF)	0		0.8		V
Supply voltage	<	V _{CC}	15		30	20	V
Peak output current		I _{OPH} /I _{OPL}	ı		±0.5		Α
Operating temperature		T _{opr}	-20	25	70	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 6: Input signal rise time(fall time)<0.5μs.

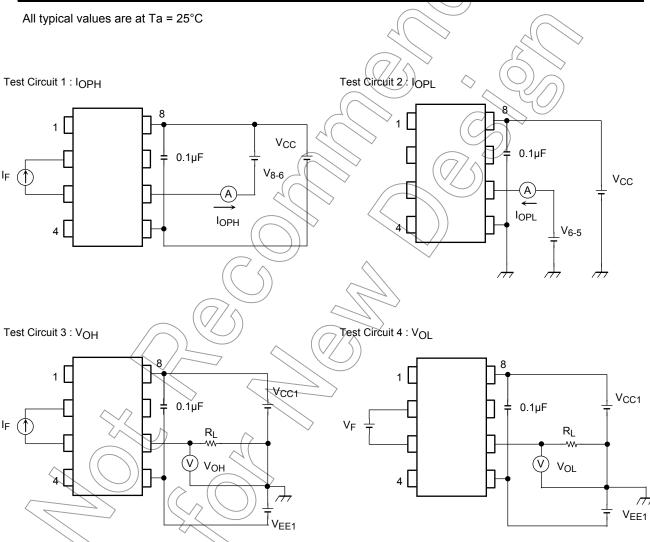
Electrical Characteristics (Ta = -20~70°C, unless otherwise specified)

Characteristic Symbol		Symbol	Test Cir– cuit	Test Condition	Min	Typ.*	Max	Unit	
Input forward voltage	;	V _F — I _F = 10 mA , Ta = 25°C		_	1.6	1.8	V		
Temperature coefficient of forward voltage		ΔV _F / ΔTa	_	I _F = 10 mA	_	-2.0	_	mV / °C	
Input reverse current		I _R	_	V _R = 5V, Ta = 25°C	->	_	10	μА	
Input capacitance		C _T	_	V = 0 , f = 1MHz , Ta = 25°C	+(45	250	pF	
Output current	"H" level	I _{OPH}	1	V _{CC} = 30V	0.5	-1.5	1	A	
Output current	"L" level	I _{OPL}	2	(*1) $I_F = 0$ $V_{6-5} = 2.5$	0.5	2	l	A	
Output voltage	"H" level	V _{OH}	3	$V_{CC1} = +15V, V_{EE1} = -15V$ R _L = 200 Ω , I _F = 5mA	15V 11 12.8 —		V		
Output voltage	"L" level	V _{OL}	4	$V_{CC1} = +15V, V_{EE1} = -15V$ $R_L = 200\Omega, V_F = 0.8V$	_	-14.2	-12.5	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
	"H" level	Іссн	_	V _{CC} = 30V, I _F = 10mA Ta = 25°C	<u></u>		1		
Supply current				V _{CC} = 30V, I _F = 10mA	_	360	// 11	- mA	
опрріу сипені	"L" level	I _{CCL}	_	$V_{CC} = 30V$, $I_F = 0$ mA Ta = 25 °C	(E)	7.5			
				$V_{CC} = 30V$, $I_F = 0mA$	<u> </u>	/ –	11		
Threshold input current	"Output L→H"	I _{FLH}		$V_{CC1} = +15V, V_{EE1} = -15V$ $R_L = 200\Omega, V_O > 0V$		1.2	5	mA	
Threshold input voltage	"Output H→L"	V _{FHL}		$V_{CC1} = +15V, V_{EE1} = -15V$ $R_L = 200\Omega, V_Q < 0V$	0.8	_	_	V	
Supply voltage		V _{CC} ((-)		10	_	35	V	
Capacitance (input-output)		C _S		V _S = 0 , f = 1MHz Ta = 25°C	_	1.0	2.0	pF	
Resistance(input-output)		RS) –	V _S = 500V , Ta = 25°C R.H.≤ 60%	1×10 ¹²	10 ¹⁴	_	Ω	

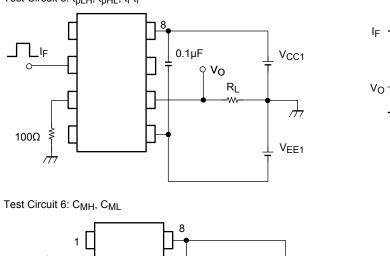


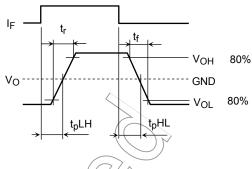
Switching Characteristics (Ta = $-20 \sim 70$ °C, unless otherwise specified)

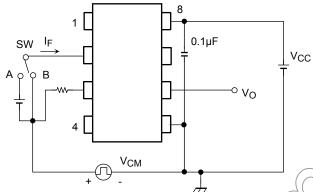
Characteristic		Symbol	Test Cir– cuit	Test Condition	Min	Typ.*	Max	Unit
Propagation	L→H	t _{pLH}	- 5	I _F = 8mA V _{CC1} = +15V, V _{FF1} = -15V	_	0.15	0.5	μs
delay time	H→L	t _{pHL}			_	0.15	0.5	
Output rise time		t _r		$R_L = 200\Omega$		_	_	μ3
Output fall time		t _f			-(/_	_	
Common mode transient immunity at high level CMH output		6	V _{CM} = 600V, I _F = 8mA V _{CC} = 30V, Ta = 25°C	-5000		_	V / µs	
Common mode transier immunity at low level output	t	C _{ML}	O	V _{CM} = 600V, I _F = 0mA V _{CC} = 30V, Ta = 25°C	5000	_	_	V / µs

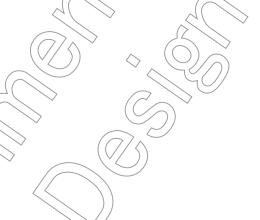


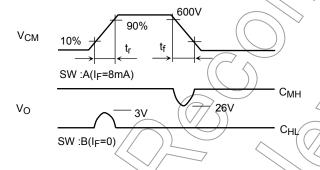
Test Circuit 5: t_{pLH}, t_{pHL}, t_r t_f

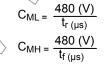




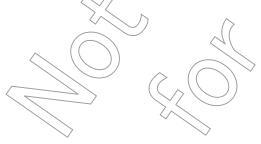


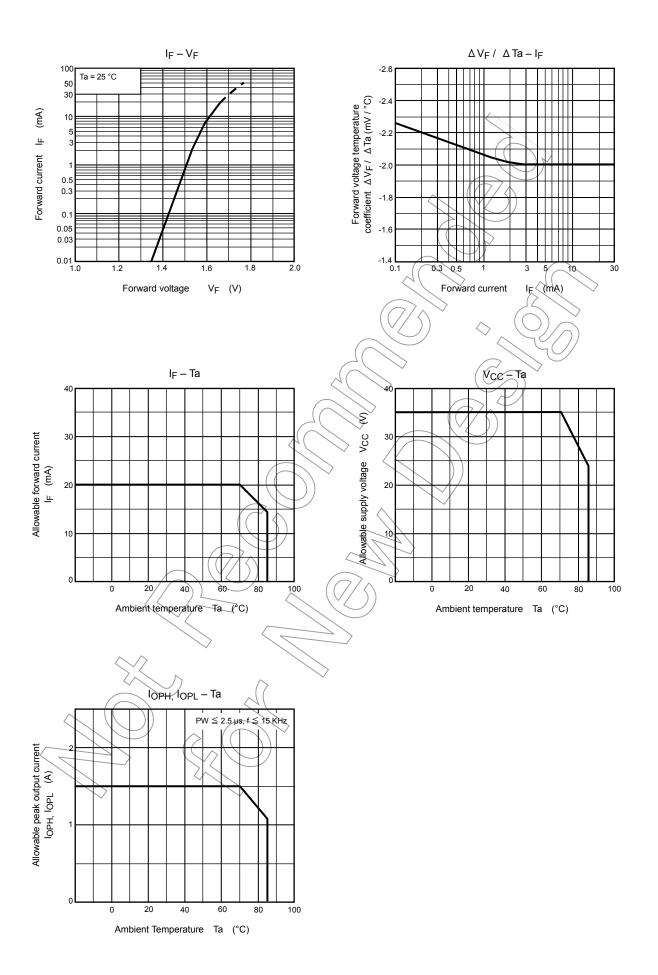






 $C_{ML}(C_{MH})$ is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.





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